# 

# S10T200C

SCHOTTKY BARRIER

RECTIFIERS

**10 AMPERES** 

200 VOLTS

### **Dual Schottky Barrier Power Rectifiers**

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to  $150^{\circ}$ C junction temperature. Typical applications are in switching Mode Power Supplies such as adaptors, DC/DC converters, free-wheeling and polarity protection diodes.

#### Features

- \* Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \* High Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory
- Flammability Classification 94V-O
- \* Pb free
- \* In compliance with EU RoHs directives

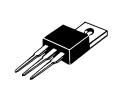


#### **MAXIMUM RATINGS**

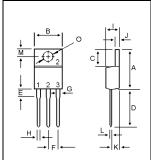
Characteristic	Symbol	S10T200C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	140	V
Average Rectifier Forward Current ( per diode ) Total Device (Rated $V_R$ ),	I <sub>F(AV)</sub>	5 10	А
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz)	I <sub>FM</sub>	10	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-ware, single phase, 60Hz)	I <sub>FSM</sub>	230	A
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

### **ELECTRICAL CHARACTERISTICS**

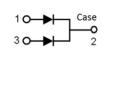
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 5 \text{ Amp } T_C = 25^{\circ}C$ ) ( $I_F = 5 \text{ Amp } T_C = 125^{\circ}C$ )	VF		1.05 0.79	1.4 	V
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_c = 25^{\circ}C$ ) ( Rated DC Voltage, $T_c = 125^{\circ}C$ )	I <sub>R</sub>		0.002 1.75	0.01	mA



TO-220AB

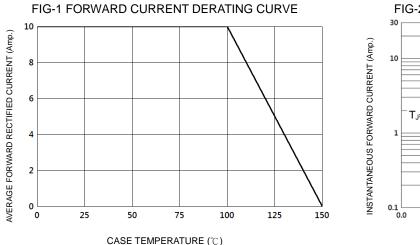


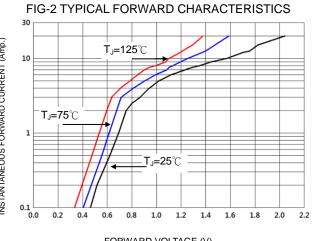
	MILLIMETERS		
DIM	MIN	MAX	
Α	14.68	16.00	
В	9.78	10.42	
С	5.02	6.60	
D	13.00	14.62	
Е	3.10	4.19	
F	2.41	2.67	
G	1.10	1.67	
н	0.69	1.01	
1	4.22	4.98	
J	1.14	1.40	
К	2.20	3.30	
L	0.28	0.61	
М	2.48	3.00	
0	3.50	4.00	





## S10T200C





FORWARD VOLTAGE (V)

#### FIG-3 TYPICAL REVERSE CHARACTERISTICS

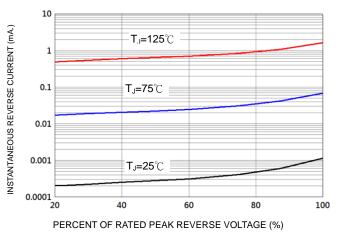


FIG-5 PEAK FORWARD SURGE CURRENT

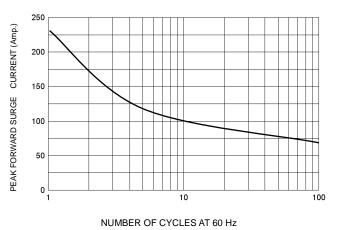


FIG-4 TYPICAL JUNCTION CAPACITANCE

